



Silicon Carbide Schottky Diode

Features

Positive temperature coefficient
Temperature-independent switching
Maximum working temperature at 175 °C
Unipolar devices and zero reverse recovery current
Zero forward recovery current
Essentially no switching losses
Reduction of heat sink requirements
High-frequency operation
Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

Package: TO-263

Terminals: Tin plated leads Polarity: As marked

Maximum Ratings (T_C=25 Unless otherwise specified

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PARAMTETER	SYMBOL	UNIT	VALUE			
Device marking code			D112010BXQG2			
Reverse voltage (repetitive peak) @ T _j =25°C	V_{RRM}	V	1200			
Reverse voltage (Surge Peak) @ T _j =25°C	V_{RSM}	V	1200			
Reverse voltage (DC) @ T _j =25°C	V_{DC}	V	1200			
Continuous forward current @ T _c =25°C		A	33			
Continuous forward current @ T _c =135°C	I _F		14			
Continuous forward current @ T _c =141°C			10			
Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	Α	85			
Power Dissipation@ T _c =25°C	D	W	158			
Power Dissipation@ T _c 4200 °C	P _{TOT}		68			
i²t Value@ Tc=25°C ,tp=10ms	i ² dt	A ² S	36			
Operating junction and Storage temperature range	T_{j} , T_{stg}	°C	-55 to +175			

Electrical Characteristics

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V _F	٧	I _F =10A, T _j =25°C	1.42	1.54
			I _F =10A, T _j =175°C	2.1	-
Poverse leekage current			V _R =1200V, T _j =25°C	1.3	13
Reverse leakage current	I _R	μA	V _R =1200V, T _j =175°C	6	-
Total capacitive charge	Q _C	nC	$V_R=800V, T_j=25^{\circ}C, QC = {}_{0}{}^{VR}C(V)dV$	53	
Total capacitance	С	pF	V _R =0V, f=1MHZ	700	-
			V _R =400V, f=1MHZ	49	-
			V _R =800V, f=1MHZ	39	-
Capacitance Stored Energy	Ec	μJ	V _R =800V	14	-

Thermal Characteristics T_a=25 Unless otherwise specified

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	R _{J-C}	°C W	0.95

Typical Characteristics

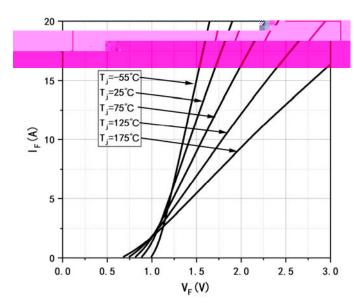


Figure 1. Forward Characteristics

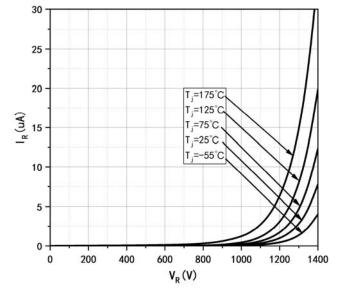
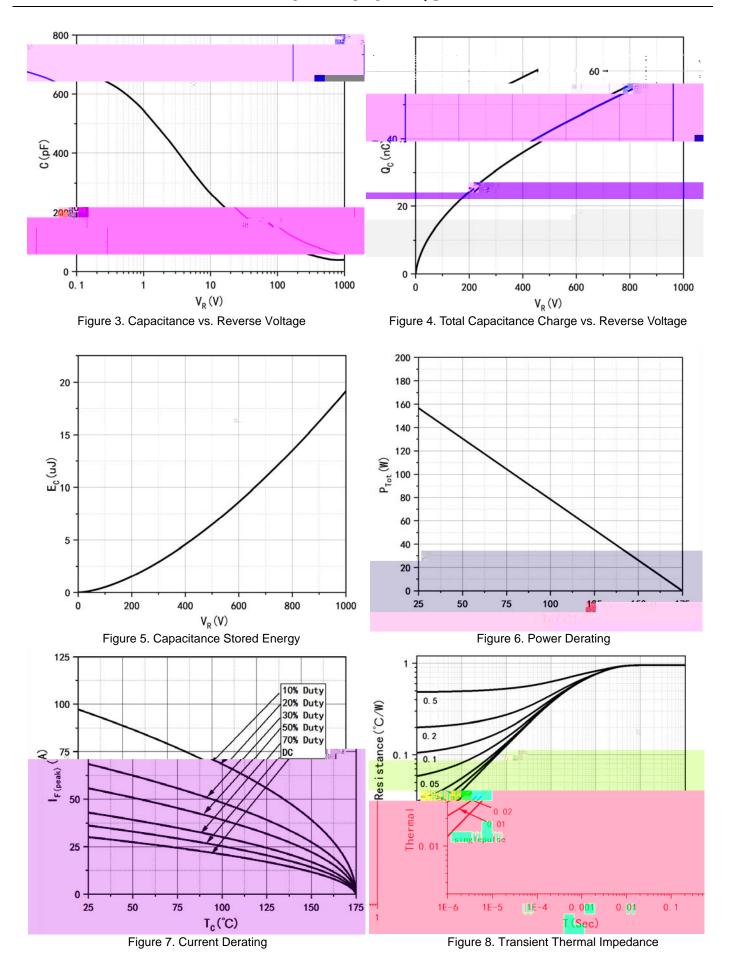


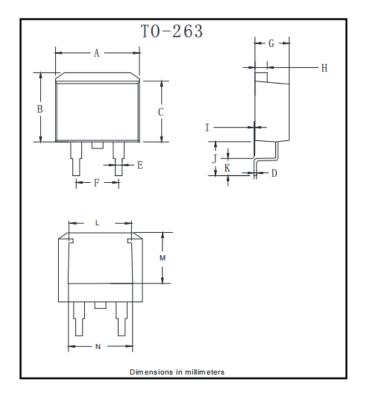
Figure 2. Reverse Characteristic

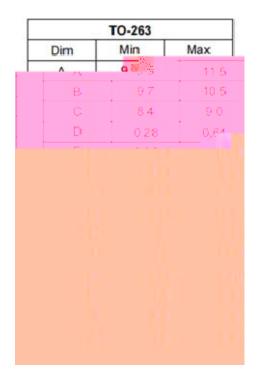






Outline Dimensions







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